

TO-92 3L

SOT-23 3L

SOT-223 4L

Tape and Reel

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2N3904TFR

MMBT3904

PZT3904

2N3904

1A

3904

2000

3000

2500

Absolute Maximum Ratings^{(1), (2)}

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol	Parameter	Value	Unit
V _{CEO}	Collector-Emitter Voltage	40	V
V _{CBO}	Collector-Base Voltage	60	V
V _{EBO}	Emitter-Base Voltage	6.0	V
۱ _C	Collector Current - Continuous	200	mA
$T_{J,}T_{STG}$	Operating and Storage Junction Temperature Range	-55 to 150	°C

Notes:

- 1. These ratings are based on a maximum junction temperature of 150°C.
- 2. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty cycle operations.

Thermal Characteristics

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Maximum			Unit
		2N3904	MMBT3904 ⁽³⁾	PZT3904 ⁽⁴⁾	Onit
р	Total Device Dissipation	625	350	1,000	mW
PD	Derate Above 25°C	5.0	2.8	8.0	mW/°C
R _{θJC}	Thermal Resistance, Junction to Case	83.3			°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	200	357	125	°C/W

Notes:

3. Device is mounted on FR-4 PCB 1.6 inch X 1.6 inch X 0.06 inch.

4. Device is mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm, mounting pad for the collector lead minimum 6 cm².

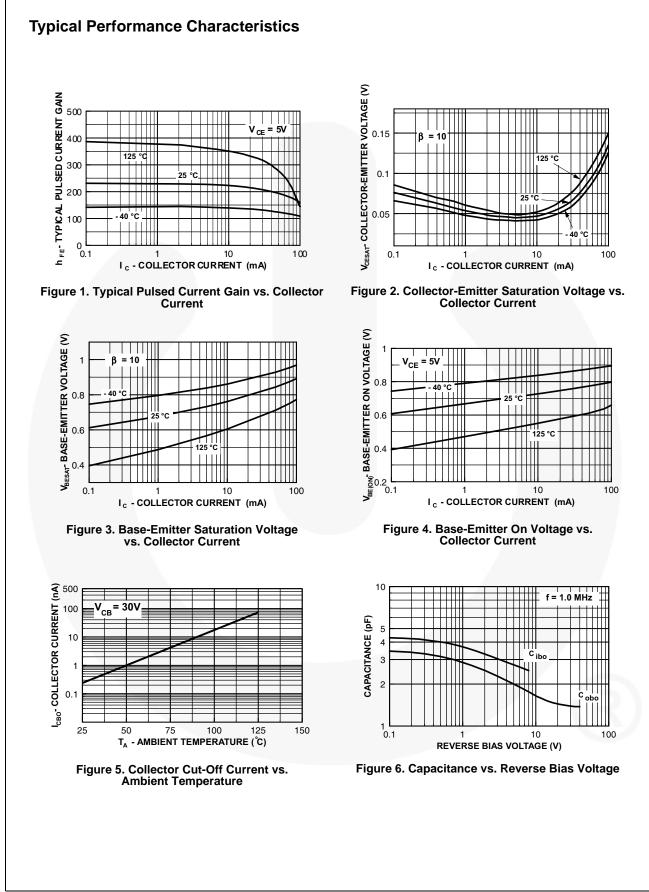
Electrical Characteristics

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

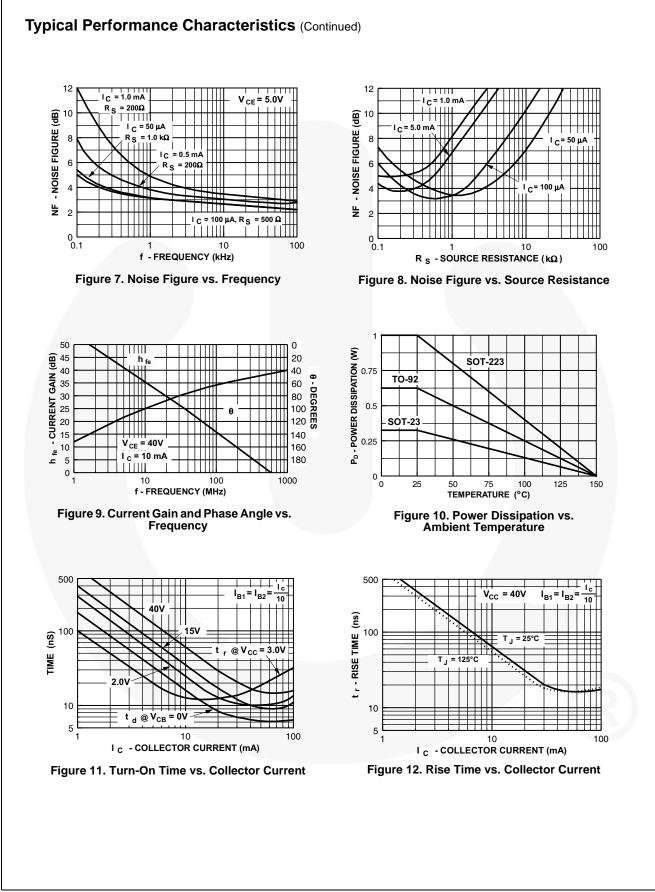
Symbol	Parameter	Conditions	Min.	Max.	Unit	
OFF CHAR	ACTERISTICS	L	-			
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 1.0 mA, I _B = 0	40		V	
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 10 μA, I _E = 0	60		V	
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 10 μA, I _C = 0	6.0		V	
I _{BL}	Base Cut-Off Current	V _{CE} = 30 V, V _{EB} = 3 V		50	nA	
I _{CEX}	Collector Cut-Off Current	V _{CE} = 30 V, V _{EB} = 3 V		50	nA	
ON CHARA	CTERISTICS ⁽⁵⁾		•	•		
		I _C = 0.1 mA, V _{CE} = 1.0 V	40			
		I _C = 1.0 mA, V _{CE} = 1.0 V	70			
h _{FE}	DC Current Gain	I _C = 10 mA, V _{CE} = 1.0 V	100	300		
		I _C = 50 mA, V _{CE} = 1.0 V	60			
		I _C =100 mA, V _{CE} = 1.0V	30			
	Collector-Emitter Saturation Voltage	I _C = 10 mA, I _B = 1.0 mA		0.2	v	
V _{CE} (sat)		I _C = 50 mA, I _B = 5.0 mA		0.3		
		I _C = 10 mA, I _B = 1.0 mA	0.65	0.85		
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C = 50 mA, I _B = 5.0 mA		0.95	- V	
SMALL SIG	NAL CHARACTERISTICS			•		
f _T	Current Gain - Bandwidth Product	$I_{C} = 10 \text{ mA}, V_{CE} = 20 \text{ V},$ f = 100 MHz	300		MHz	
C _{obo}	Output Capacitance	$V_{CB} = 5.0 \text{ V}, I_E = 0,$ f = 100 kHz		4.0	pF	
C _{ibo}	Input Capacitance	V _{EB} = 0.5 V, I _C = 0, f = 100 kHz		8.0	pF	
NF	Noise Figure	I_{C} = 100 μA, V _{CE} = 5.0 V, R _S = 1.0 kΩ, f = 10 Hz to 15.7 kHz		5.0	dB	
SWITCHING	CHARACTERISTICS	L				
t _d	Delay Time	V _{CC} = 3.0 V, V _{BE} = 0.5 V		35	ns	
t _r	Rise Time	$I_{\rm C} = 10 \text{ mA}, I_{\rm B1} = 1.0 \text{ mA}$		35	ns	
t _s	Storage Time	V _{CC} = 3.0 V, I _C = 10 mA,		200	ns	
t _f	Fall Time	$I_{B1} = I_{B2} = 1.0 \text{ mA}$		50	ns	

Note:

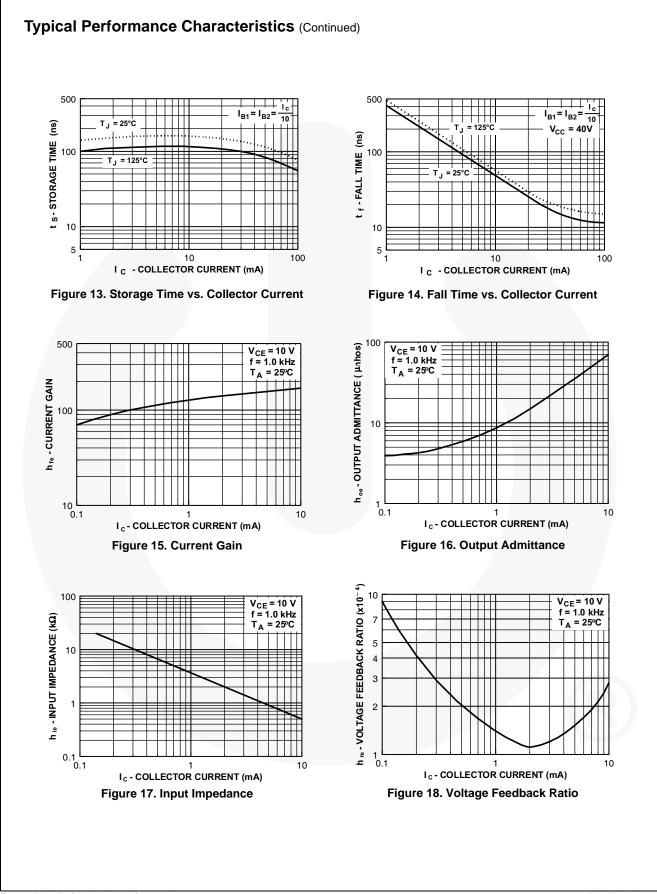
5. Pulse test: pulse width \leq 300 $\mu s,$ duty cycle \leq 2.0%.

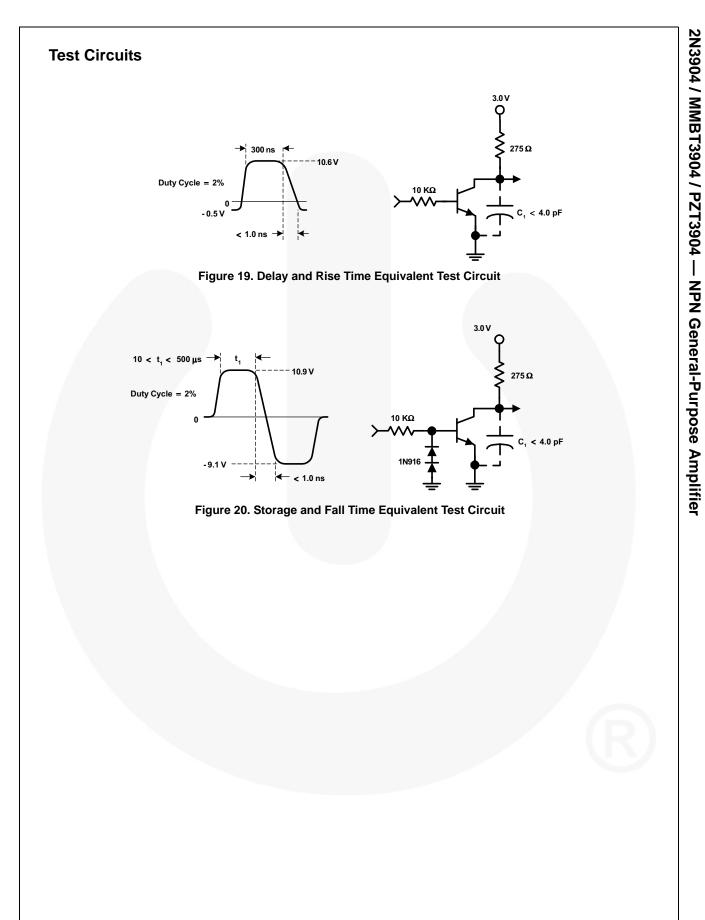


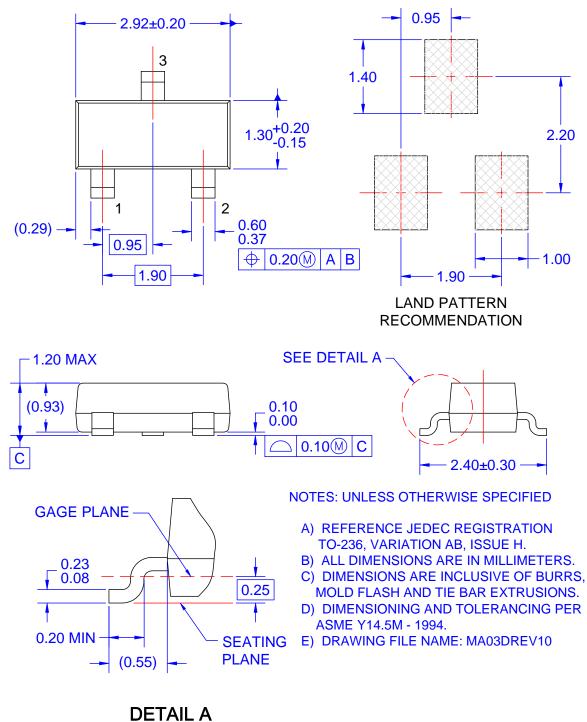
2N3904 / MMBT3904 / PZT3904 — NPN General-Purpose Amplifier



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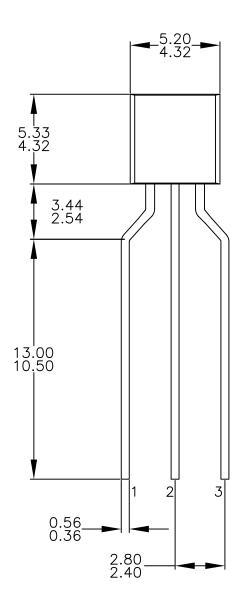


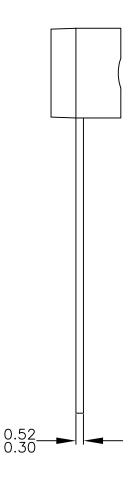




SCALE: 2X

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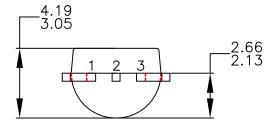


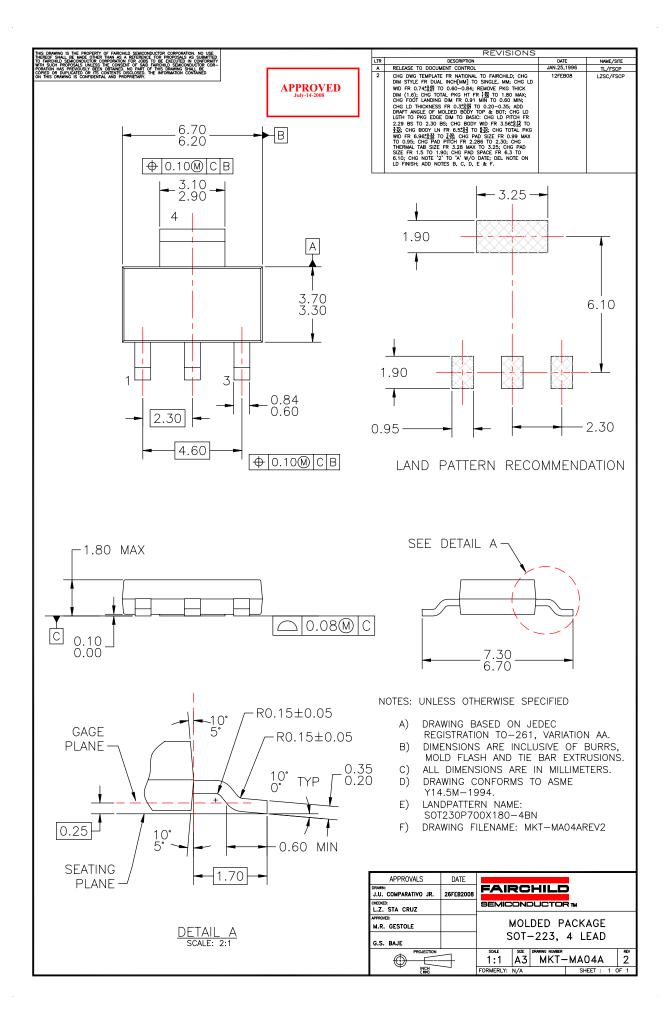


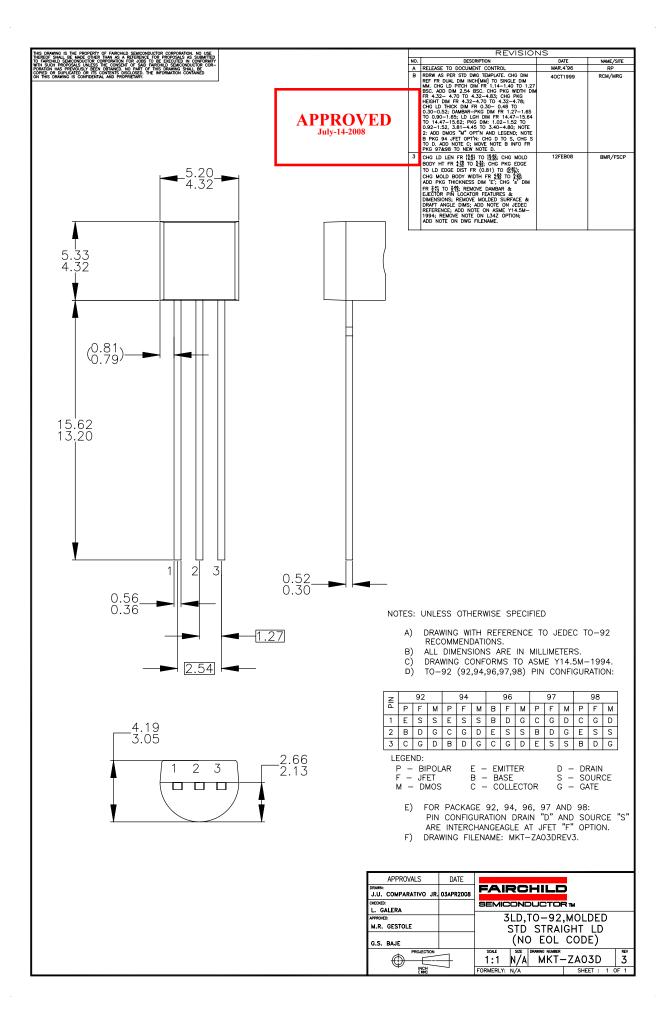
NOTES: UNLESS OTHERWISE SPECIFIED

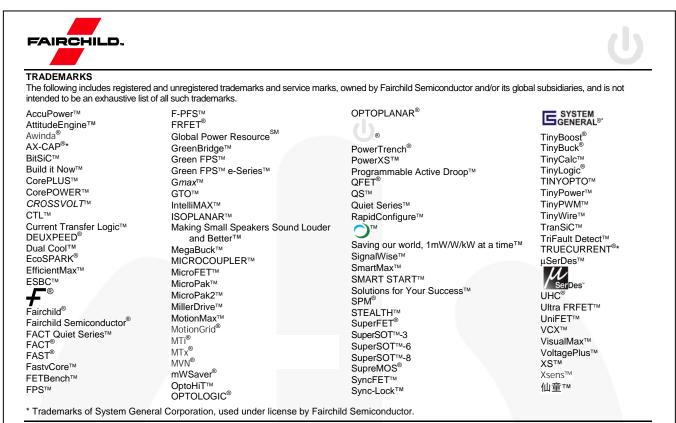
- DRAWING CONFORMS TO JEDEC MS-013, VARIATION AC. ALL DIMENSIONS ARE IN MILLIMETERS. DRAWING CONFORMS TO ASME Y14.5M-2009. DRAWING FILENAME: MKT-ZA03FREV3. FAIRCHILD SEMICONDUCTOR. Α.

- В. С. D. Е.









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